Simulation of the interaction between a 2G HTS stack and a traveling inhomogeneous magnetic field

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Outline

- Motivation
- > Objectives
- Introduction
- > The model
- > Results
- Final Considerations

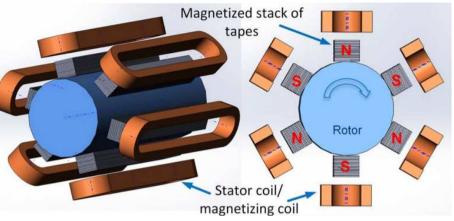


Motivation: Electric Machines with stacks of 2G tapes

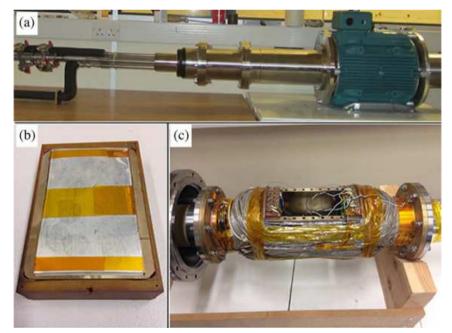


X. Granados et. al. EUCAS-2015, Lyon.

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A. Patel et. al., IEEE Trans. on App. Supercond., 25 (3), 2015.



M. Baghdadi et al., IEEE Trans. on App. Supercond., 25 (3), 2015

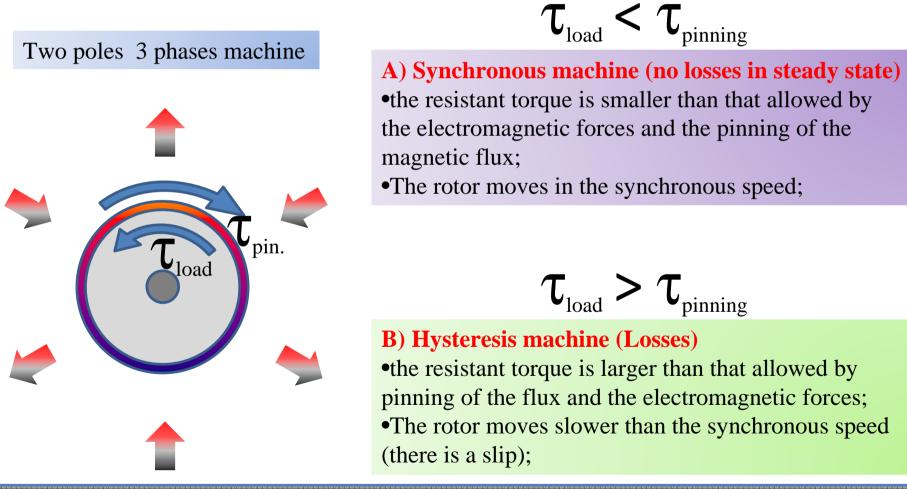


- To simulate the interaction between a travelling inhomogeneous magnetic field and a 2G tape HTS stack
- To compare the simulated results with measurements
- To extrapolate the model to investigate the influence of some parameters change



Trapped field motors

The magnetic field rotates and the superconductor magnetizes (partially or fully) according to the applied magnetic field

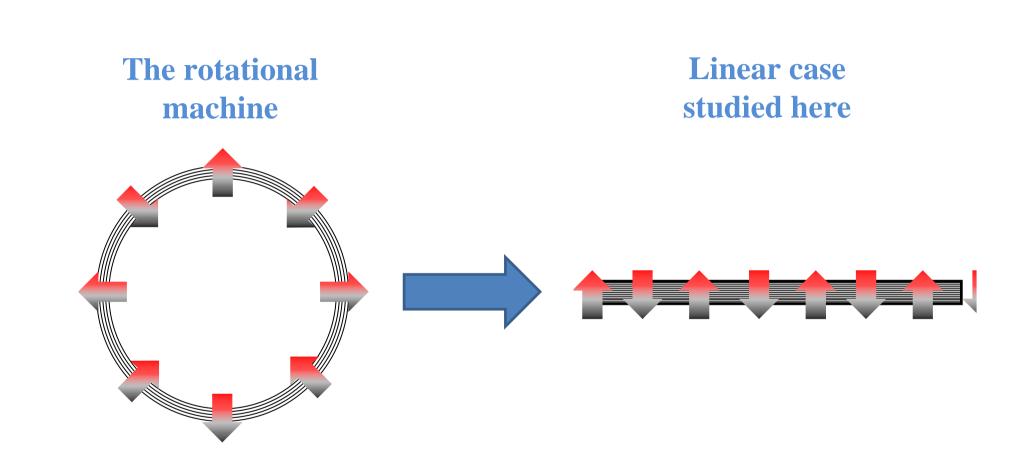


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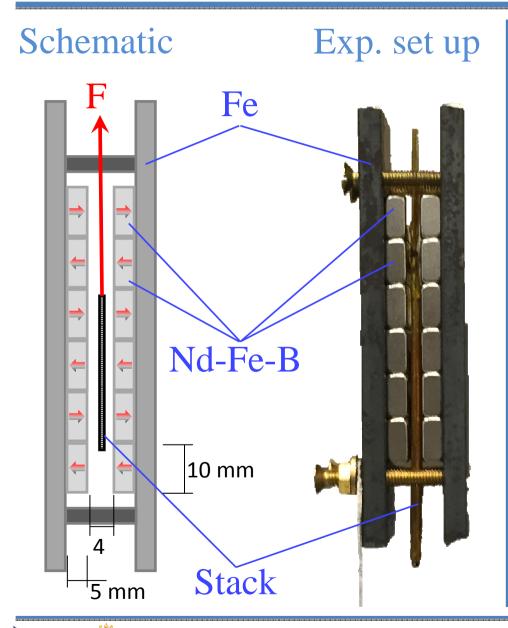


2G HTS Electric Motors





Studied System



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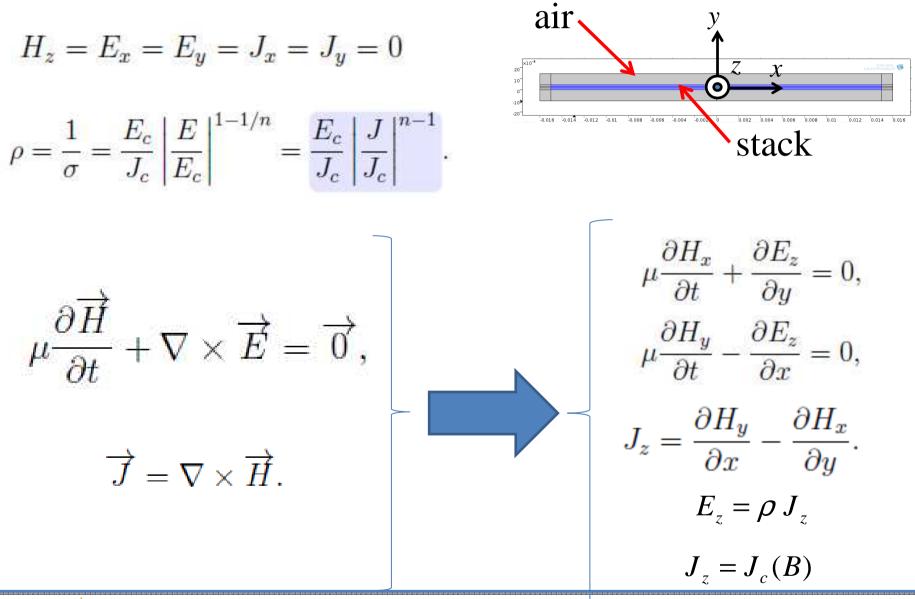
Stack



SuperPower SF12050-AP (2013) $I_{c av.} = 281 \text{ A (Self Field, 77 K)}$ n = 35 (Self Field, 77 K) 9 layersWidth = 12 mm Length = 30 mm Thickness total = 510 µm

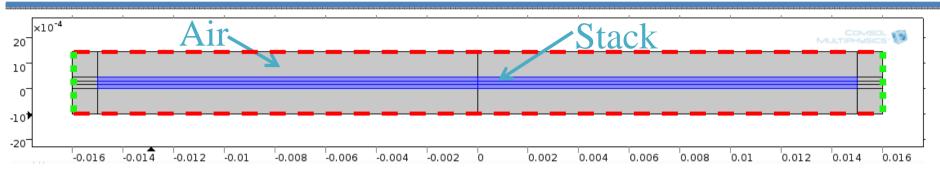


The H-formulation (2D)

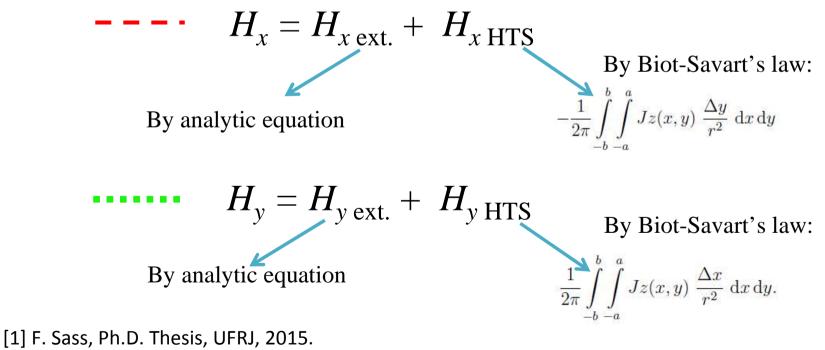




The H-formulation (2D): FEM-BEM



H-Formulation with edge elements: boundary conditions

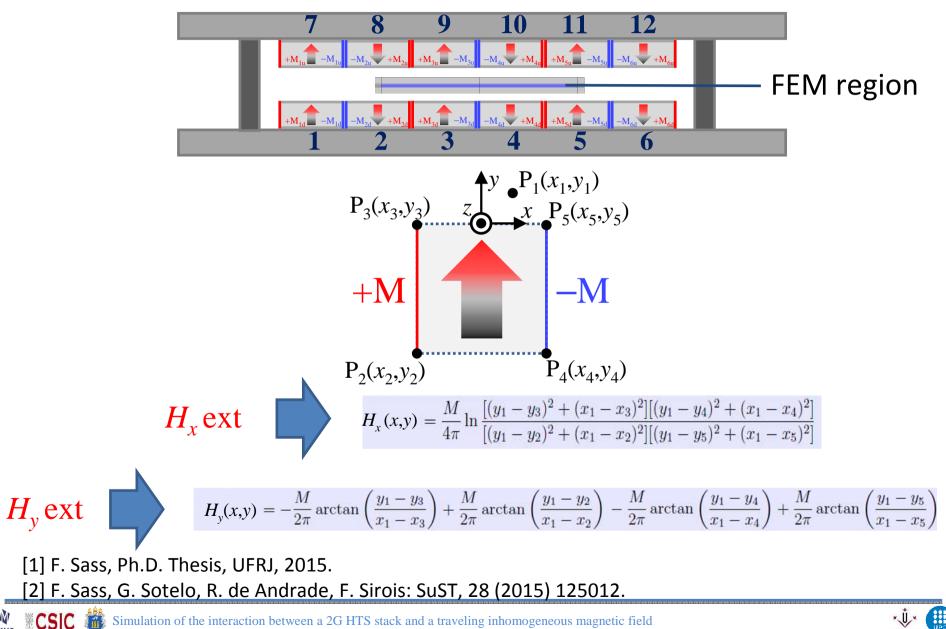


[2] F. Sass, G. Sotelo, R. de Andrade, F. Sirois: SuST, 28 (2015) 125012.

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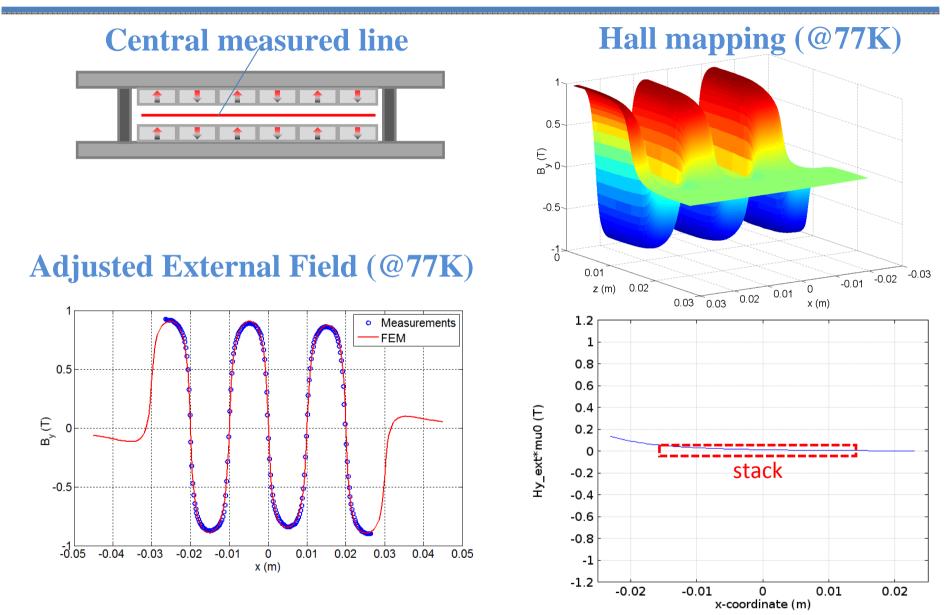
Permanent Magnets Analytic Equations



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Magnetic Field Results



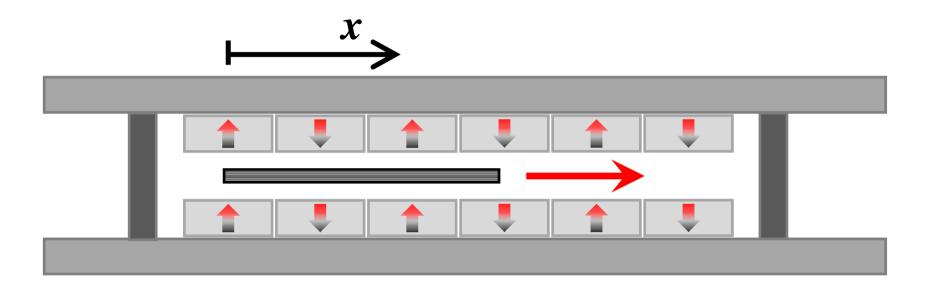


Results



Stack displacement

The stack was displaced at a constant speed:

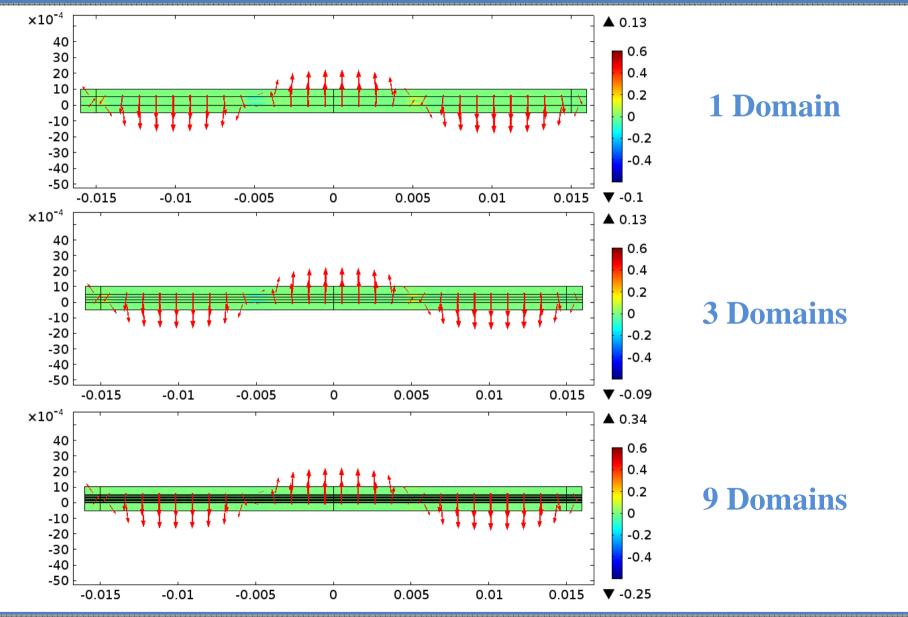


Two speeds were measured to be compared with simulations: $v_1 = 0.344$ mm/s; $v_2 = 0.2066$ mm/s.



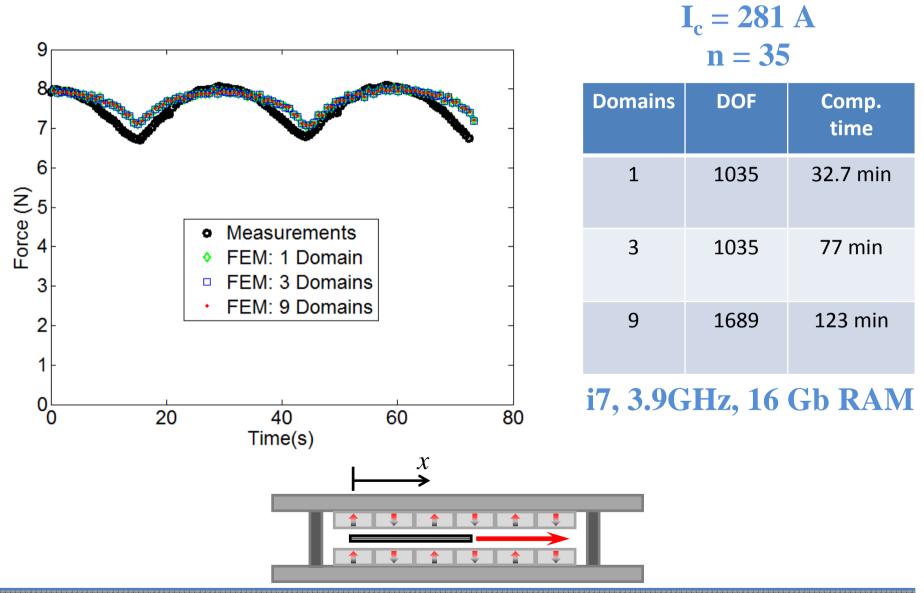


Homogenized domains and induced currents





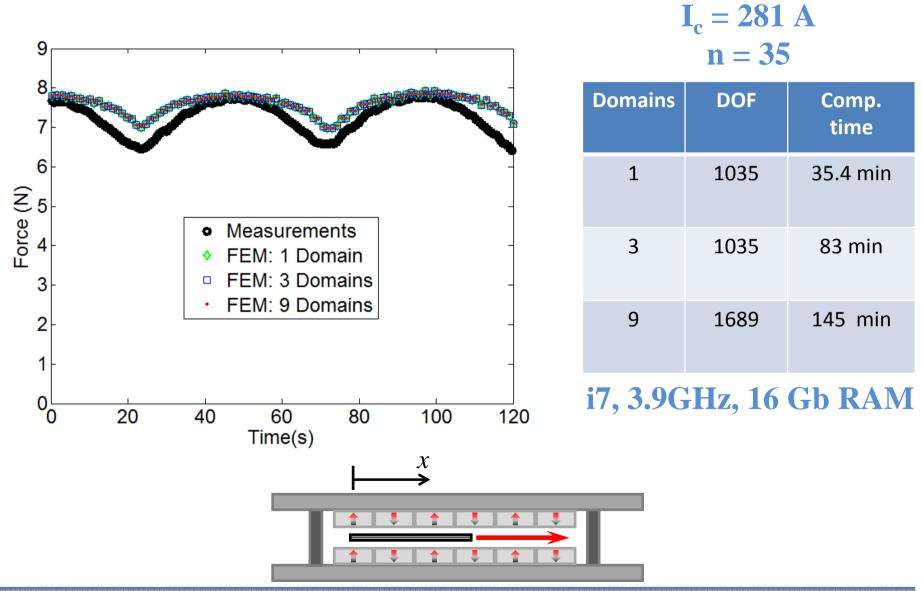
Force Results: v = 0.344 mm/s



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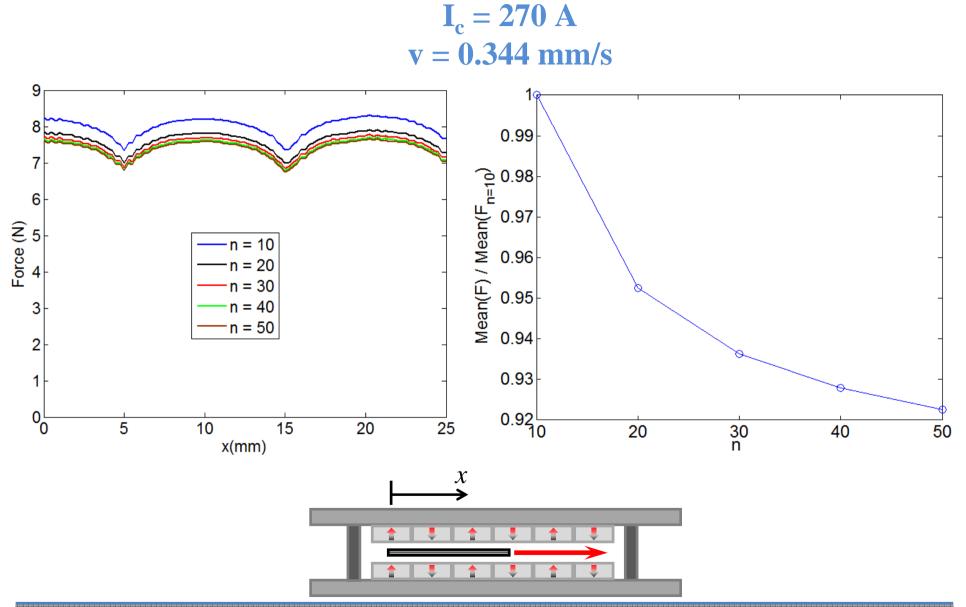


Force Results: v = 0.207 mm/s



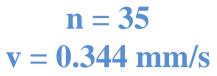


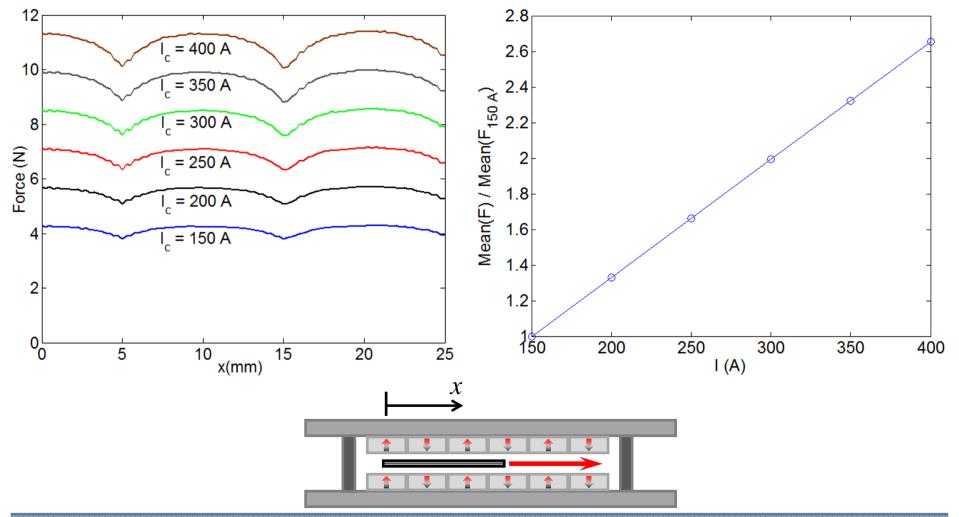
Force Results: n influence





Force Results: I_c influence

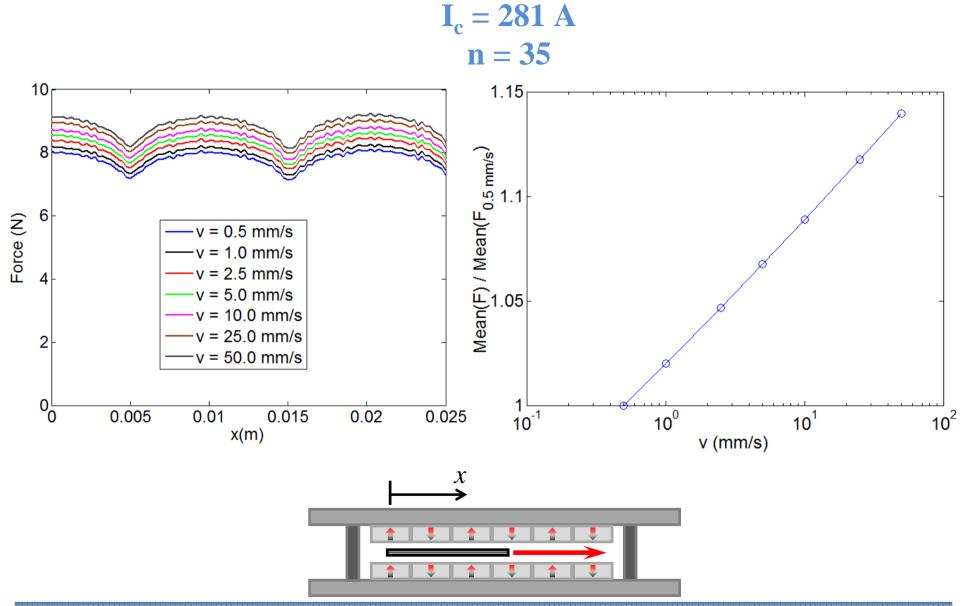




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Force Results: speed influence





Final Considerations

- The H-formulation with FEM-BEM is an interesting way for modelling the interaction between a traveling magnetic field and a stack of 2G HTS tapes
- The model can be applied to the project HTS machines (stacks or bulks)
- It was possible to calculate very fast the proposed problem (~30 min, 1 domain)
- The model was extrapolated and some parameters were changed to investigate their influence into the force

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